








	<h2>SI1023X-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI1023X-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2P-CH 20V 0.37A SC89-6</p> <p>Datenblätter:  SI1023X-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 52285 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1023X-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 20V 0.37A SC89-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	52285 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	370mA
Rds On (Max) @ Id, Vgs	1.2 Ohm @ 350mA, 4.5V
VGS (th) (Max) @ Id	450mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	1.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI1023X-T1-GE3 ist neu im Original, Suche SI1023X-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1023X-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1023X-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1024-868-A-DK Energy Micro (Silicon Labs) KIT DEV WIRELESS SI1024 868MHZ</p>	 <p>SI1024-A-GMR Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1023X VISHAY SI1023X VISHAY</p>	 <p>SI1024-A-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>
 <p>SI1023X-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 0.37A SOT563F</p>	 <p>SI1023X-T1 VISHAY SI1023X-T1 VISHAY</p>	 <p>SI1023X-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 0.37A SC89-6</p>	 <p>SI1023CX-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V SC89-6</p>

heiße Teile

Mehr

 SI1013X-T1-E3	 SI1013X-T1-GE3	 SI1013X-T1-GE3	 SI1016CX-T1-GE3	 SI1016CX-T1-GE3
 SI1016X-T1-E3	 SI1016X-T1-E3	 SI1016X-T1-GE3	 SI1016X-T1-GE3	 SI1016X2-T1-GE3
 SI1021R-T1	 SI1021R-T1-E3	 SI1021R-T1-E3	 SI1022R-T1	 SI1022R-T1-E3
 SI1022R-T1-E3	 SI1022R-T1-GE3	 SI1022R-T1-GE3	 SI1022R-TI-E3	 SI1023CX-T1-GE3
 SI1023CX-T1-GE3	 SI1023X-T1	 SI1023X-T1-E3	 SI1023X-T1-E3	 SI1023X-T1-GE3
 SI1024-T1	 SI1024X-T1	 SI1024X-T1-E3	 SI1024X-T1-E3	 SI1024X-T1-GE3
 SI1024X-T1-GE3	 SI1024X-TI-GE3	 SI1025X-T1	 SI1025X-T1-E3	 SI1025X-T1-E3
 SI1026X-T1	 SI1026X-T1-E3	 SI1026X-T1-E3	 SI1026X-T1-GE3	 SI1026X-T1-GE3
 SI1028X-T1-GE3	 SI1028X-T1-GE3	 SI1029X-T1-GE3	 SI1029X-T1-GE3	 SI1031R-T1
 SI1031R-T1-E3	 SI1031R-T1-E3	 SI1031R-T1-GE3	 SI1031R-T1-GE3	 SI1031X-T1

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